NSN 5961-00-926-2568

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View Online at https://aerobasegroup.com/nsn/5961-00-926-2568
Inclosure Material:
Metal
Overall Length:
Between 0.330 inches and 0.380 inches
Overall Diameter:
Between 0.525 inches and 0.645 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Internal Junction Configuration:
Pnp
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.164 inches
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
-80.0 collector to base voltage/static/emitter open and -55.0 collector to emitter voltage/static/base open and -28.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
3.50 amperes source cutoff current blank
Power Rating Per Characteristic:
11.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unc
Terminal Type And Quantity:
3 tab, solder lug
Specification Data:
81349-mil-s-19500/38 government specification
Shelf Life:

Unit Of Measure:

N/a

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